NSN 5961-01-089-2198



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-089-2198 **Inclosure Material:** Metal **Overall Length:** Between 1.397 inches and 1.525 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-63 **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case **Overall Width Across Flats:** Between 0.855 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 325.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 15.00 amperes source cutoff current and 70.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire hook Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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